EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	863	703/6.ccls.	US-PGPUB; USPAT; EPO; DERWENT	OR .	OFF	2007/02/27 16:25

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	46	local adj flare	US-PGPUB; USPAT; EPO; DERWENT	OR	OFF	2007/02/27 17:15
L2	4	("20030068565" "20040021854" "20040196447" "6233056").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/02/27 17:32
L3	4573	flar\$3 and mask	US-PGPUB; USPAT; EPO; DERWENT	OR	OFF	2007/02/27 17:33
L4	1367	L3 and (lithography or photolithography)	US-PGPUB; USPAT; EPO; DERWENT	OR	OFF	2007/02/27 17:35
L6	364	L4 and (OPC or correction)	US-PGPUB; USPAT; EPO; DERWENT	OR	OFF	2007/02/27 17:52
L7	. 4	("20040205688" "20050055658" "6303253" "6763514").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/02/27 18:16

"local flare"

1950

2004

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Did you mean: "local flair"

R Hynes K Nandra

E Gotthelf layouts - group of 3

E Gottheif E Robinson

E Robinson L Ericsson Effectiveness and confirmation of local area flare measurement method in various pattern layouts - group of 3 »

D Nam, E Lee, S Jung, YS Kang, G Yeo, J Lee, H Cho ... - Proc. SPIE, 2002 - spie.org ... The LOAFER is designed to measure the local area flare of the lens, that is, the short and mid-range flare and the **local flare** distribution of the exposure ...

Cited by 4 - Related Articles - Cached - Web Search

<u>Development of 157-nm full-field scanners - group of 3 »</u>
H Hata, H Nogawa, S Suda - Proceedings of SPIE, 2004 - link.aip.org
... When compared to ArF, **local flare** increases significantly. However, it has been confirmed that **local flare** can be greatly mitigated ...

Cited by 3 - Related Articles - Web Search

Local flare effects and correction in ArF lithography - group of 2 »

T Yao, M Osawa, T Minami, N Yamamoto, H Aoyama, G ... - VLSI Technology, 2003. Digest of Technical Papers. 2003 ..., 2003 - ieeexplore.ieee.org

Page 1. 4B-1 **Local Flare** Effects and Correction in ArF Lithography Teruyoshi Yao, Morimi Osawa, Takayoshi Mind , Norihiro Yamamoto, Hajime Aoyama, Genshi Okuda, ...

Cited by 1 - Related Articles - Web Search

<u>Unsteady Aerodynamics of an Ablating Flared Body of Revolution Including Effect of Entropy Gradient - group of 2 »</u>

LE Ericsson - AZAA Journal, 1968 - pdf.aiaa.org

 \dots local flare forces become dynamically destabilizing. \dots 2 and the local "flare efficiency" type of effects can easily be compted. It \dots

Cited by 8 - Related Articles - Web Search

Correction for local flare effects approximated with double Gaussian profile in ArF lithography - group of 4 »

M Osawa, T Yao, H Aoyama, K Ogino, H Hoshino, Y ... - Journal of Vacuum Science & Technology B: Microelectronics ..., 2003 - link.aip.org

... been developed for correcting line width variations due to midrange flare with a scattering range of over a few tens of micrometers (which we call **local flare** ...

Cited by 1 - Related Articles - Web Search - BL Direct

<u>Application of Realistic Model Atmospheres to Eclipse Maps of Accretion Disks: The Effective ... - group of 3 »</u>

EL Robinson, JH Wood, RA Wade - The Astrophysical Journal, 1999 - journals uchicago edu ... 4 1 at the outer edge, giving h/r r. This latter relation yields a slope of dh/dr 0.1 at the outer edge of the disk, corresponding to a **local flare** angle of ... Cited by 9 - Related Articles - Web Search - BL Direct

The Properties of the Relativistic Iron K-Line in NGC 3516 - group of 7 »

K Nandra, IM George, RF Mushotzky, TJ Turner, T ... - The Astrophysical Journal, 1999 - journals uchicago.edu

... the variation in the blue wing could be due to an enhancement in the illuminating flux of the inner disk portion moving toward us, due to a **local flare** (cf. ...

Cited by 117 - Related Articles - Web Search - BL Direct

Relevance of TCAD to process-aware design - group of 6 »

murai "area density"

1950

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- 2004

All Results

F Murai

H Yoda

Y Zheng

M Osawa S Okazaki Fast proximity effect correction method using a pattern area density map - group of 4 » F Murai, H Yoda, S Okazaki, N Saitou, Y Sakitani - Journal of Vacuum Science & Technology B:

Microelectronics 1002 link oit

Microelectronics ..., 1992 - link.aip.org ... using a pattern **area density** map. [Journal of Vacuum Science & Technology B:

Microelectronics and Nanometer Structures 10, 3072 (1992)]. Fumio Murai, Haruo Yoda ...

Cited by 17 - Related Articles - Web Search - BL Direct

Proximity effect correction using pattern shape modification and area density map for electron-beam ... - group of 4 »

M Osawa, K Takahashi, M Sato, H Arimoto, K Ogino, ... - Journal of Vacuum Science & Technology B:

Microelectronics ..., 2001 - link.aip.org

Proximity effect correction using pattern shape modification and area density

map for electron-beam projection lithography. [Journal ...

Cited by 9 - Related Articles - Web Search - BL Direct

Pattern fabrication method using a charged particle beam and apparatus for realizing same - group of 5 »

H Yoda, F Murai - US Patent 5,278,421, 1994 - Google Patents

... ACHARGED PARTICLE BEAM AND APPARATUS FOR REALIZING SAME [75] Inventors: Haruo Yoda;

Fumio Murai, both of ... posed is extremely small and that the area density ...

Cited by 7 - Related Articles - Web Search

Greater number of microtubules per axon of unmyelinated fibers of mutant quails deficient in ... - group of 3 »

..., M Mizutani, T Yamamoto, H Hayashi, Y **Murai** - Acta Neuropathologica, 1994 - Springer

... JX Zhao - A. Ohnishi () 9 T. Yamamoto 9 Y. **Murai** Department of Neurolog); University of ... NF per axon and per m 2 of the transverse axonal **area** (**density**) were cal ...

Cited by 6 - Related Articles - Web Search - BL Direct

<u>Variation in bone mineral density of the sacrum in young adults and its significance for sacral ...</u> - group of 4 »

Y Zheng, WW Lu, Q Zhu, L Qin, S Zhong, JC Leong - Spine, 2000 - spinejournal.com ... calculated from quantitative computed tomography (QCT), was used to obtain area

density (g/cm ... Okuyama K, Sato K, Abe E, Inaba H, Shimada Y, Murai H. Stability ...

Cited by 16 - Related Articles - Web Search - BL Direct

Proximity effect correction using pattern shape modification and area density map - group of 4 »

K Takahashi, M Osawa, M Sato, H Arimoto, K Ogino, ... - Journal of Vacuum Science & Technology B: Microelectronics ..., 2000 - link.aip.org

... F. Murai, H. Yoda, S. Okazaki, N. Saitou, and Y. Sakitani, "Fast proximity effect

correction method using a pattern area density map," J. Vac. Sci. ...

Cited by 3 - Related Articles - Web Search - BL Direct

<u>Proximity-effect correction for EPL by using multiple pattern-area- density maps and pattern ... - group of 5 »</u>

F Murai, H Fukuda, S Mori, A Sato, K Nakajo - Proceedings of SPIE, 2003 - spie.org Abstract. PUBLICATIONS. Proximity-effect correction for EPL by using multiple pattern-area- density maps and pattern classification Murai, Fumio, Hitachi, Ltd. ...

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Image area discriminating system for an image processing apparatus - group of 2 »



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AbstractPlus | Full Text: PDF(232 KB) | IET CNF

flare simulation opc

1950 - 2004 Search

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A Erdmann

M McKean

A Ray-Chaudhur...

R Winglee

G Dulk

Model-based OPC/DRC considering local flare effects - group of 3 »

H Futatsuya, T Yao, M Osawa, K Ogino, H Hoshino, H ... - Proceedings of SPIE, 2004 - link.aip.org ... including local flare effects, and its results. The simulation results show good

agreement with the experimental results, indicating that effective OPC/DRC ...

Web Search

New process models for OPC at sub-90-nm nodes - group of 6 »

Y Granik, NB Cobb - Proceedings of SPIE, 2003 - perso.enst-bretagne.fr

... Optical flare CMPnon- uniformity Illuminator optics ... Outside of the modeling range,

the target bias OPC will be used PRINTimage simulation contours Figure 10. ...

Cited by 3 - Related Articles - View as HTML - Web Search

Relevance of TCAD to process-aware design - group of 6 »

VK Singh, J Garcia-Colevatti - Proceedings of the SPIE, 2002 - uos.ac.kr

... Impact of aberrations on design – Layout dependent flare in EUV ... simulation Page 20.

TCAD ... models to build/strengthen OPC models Complexity Run time Aerial ...

Cited by 1 - Related Articles - View as HTML - Web Search

Relevance of technology computer aided design (TCAD) to process-aware design

V Singh, J Garcia-Colevatti - Journal of Microlithography, Microfabrication, and ..., 2002 - link.aip.org

... with one of the areas within TCAD, lithography simulation. ... In addition to OPC and

the short-range effects ... such effects are lens aberrations and flare, with the ...

Related Articles - Web Search - BL Direct

Transistor flaring in deep submicron-design considerations - group of 5 »

V Singhal, CB Keshav, KG Sumanth, PR Suresh - Design Automation Conference, 2002. Proceedings of ASP-DAC ..., 2002 - ieeexplore.ieee.org

... 4.1 Designing out flares- A solution for high ... Our analysis with statistical simulation

results showed that we ... Most OPC based corrective schemes, which involve ...

Related Articles - Web Search

Limits of strong phase-shift patterning for device research - group of 7 »

M Fritze, RD Mallen, B Wheeler, D Yost, JP Snyder, ... - Proceedings of SPIE, 2003 - photronics.com

... test cells, no clear influence of long range flare ... Fig 6: IC Workbench aerial image

simulation of transistor gate with and without OPC described in ...

Cited by 3 - Related Articles - View as HTML - Web Search

Propagation and absorption of electron-cyclotron maser radiation during solar flares -

aroup of 4 »

ME McKean, RM Winglee, GA Dulk - Solar Physics, 1989 - Springer

... could provide the heating necessary to explain some soft X-ray features observed

in solar flares. ... 0 = 90, opc/12 e = 0.3, oph/2 e = 0.03, and Ls = 105 km. ...

Cited by 30 - Related Articles - Web Search

Potential issues on optical proximity correction (OPQ) using double dipole lithography

TB Chiou, S Hsu, M Eurlings, E Hendrickx, A Chen - Microprocesses and Nanotechnology Conference,

2004. Digest ..., 2004 - ieeexplore.ieee.org

... to describe the short- and mid-range flare as a ... be used as an input parameter in

the lithography simulator. ... is able to improve the accuracy of OPC calibration. ... Related Articles - Web Search

Comparison of simulation approaches for chemically amplified resists - group of 5 » A Erdmann, W Henke, S Robertson, E Richter, B ... - Proc. SPIE, 2001 - sigma-c.de

flare opc

1950

2004

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Correction for local flare effects approximated with double Gaussian profile in ArF lithography - group of 4 »

R Winglee

M Osawa, T Yao, H Aoyama, K Ogino, H Hoshino, Y ... - Journal of Vacuum Science & Technology B:

G Dulk Microelectronics 2003 - link.aip.org

... to local flare intensity and is independent of pattern layout considering the order

of the local flare correction (LFC) and optical proximity correction (OPC). ...

Cited by 1 - Related Articles - Web Search - BL Direct

M McKean M Endl

B Lin

Model-based OPC/DRC considering local flare effects - group of 3 »

H Futatsuya, T Yao, M Osawa, K Ogino, H Hoshino, H ... - Proceedings of SPIE, 2004 - link.aip.org

... OPC/DRC using this method is possible. Model-based OPC/DRC considering local

flare effects. [Proceedings of SPIE 5377, 451 (2004)]. ...

Web Search

[ciτατιον] Model-based OPC/DRC considering local flare effects [5377-40]

H Futatsuya, T Yao, M Osawa, K Ogino, H Hoshino, H ... - PROCEEDINGS-SPIE THE INTERNATIONAL

SOCIETY FOR OPTICAL ..., 2004 - International Society for Optical Engineering: 1999

Web Search - BL Direct

Investigation of stray light characteristic by multiple Gaussian modeling and its OPC

application - group of 3 »

HC Kim, DS Nam, GS Yeo, SJ Lee, SG Woo, HK Cho, WS ... - Proceedings of SPIE, 2004 - link.aip.org

... scattering range characteristic of flare. To minimize CD errors from OPC, flare

level and EOR should be considered in the OPC procedure. ...

Web Search

Relevance of TCAD to process-aware design - group of 6 »

VK Singh, J Garcia-Colevatti - Proceedings of the SPIE, 2002 - uos.ac.kr

... ò Focus on aspects of Lithography - Design coupling - Some challenges in OPC -

Impact of aberrations on design - Layout dependent flare in EUV ...

Cited by 1 - Related Articles - View as HTML - Web Search

... of techniques to measure the point spread function due to scatter and **flare** in EUV

lithography ... - group of 4 »

M Chandhok, SH Lee, CG Krautschik, G Zhang, BJ ... - Proceedings of SPIE, 2004 - spie.org

... expected that to meet the CD control requirements for the 32 nm node, Flare Variation

Compensation (FVC), akin to Optical Proximity Correction (OPC) would be ...

Cited by 4 - Related Articles - Cached - Web Search

Test structure for fixing OPC of 200 nm pitch via chain using inner and outer dummy via array - group of 2 »

T Nasuno, Y Matsubara, A Minami, N Uchida, H ... - Microelectronic Test Structures, 2004. Proceedings.

ICMTS'04 ..., 2004 - ieeexplore.ieee.org

... width and length of dummy patterns are shrunk drastically by OPE and local flare

effect, However, inner pattern can be protected. In the case of OPC A, length ...

Related Articles - Web Search

New process models for OPC at sub-90-nm nodes - group of 6 »

Y Granik, NB Cobb - Proceedings of SPIE, 2003 - perso.enst-bretagne.fr

... hard because the flare has long interaction range, which results in the destruction

of the design hierarchy and consequential explosion of OPC runtime. ...

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flare calculation opc

1950

2004 Search

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F Rouesnel

S Els

A Kaufer

S Brillant

Correction for local flare effects approximated with double Gaussian profile in ArF

M Endl <u>lithography</u> - group of 4 »

M Osawa, T Yao, H Aoyama, K Ogino, H Hoshino, Y ... - Journal of Vacuum Science & Technology B:

Microelectronics ..., 2003 - link.aip.org

... The CD variation due to local flare was reduced from 22 ... GB of memory each) were used

to calculate each process ... processing times are much faster than the OPC ones ...

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<u>Propagation and absorption of electron-cyclotron maser radiation during solar flares</u> - group of 4 »

ME McKean, RM Winglee, GA Dulk - Solar Physics, 1989 - Springer

... to explain some soft X-ray features observed in solar flares. ... 0 = 90, opc/12 e =

0.3, oph/2 e = 0.03 ... Plotted are: Equation (11) (solid line) and numeri- cal ...

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VK Singh, J Garcia-Colevatti - Proceedings of the SPIE, 2002 - uos.ac.kr

... ò Focus on aspects of Lithography – Design coupling – Some challenges in OPC –

Impact of aberrations on design – Layout dependent flare in EUV ...

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Orientation dependent shielding for use with dipole illumination techniques

DFUSUS HSU, NUS CORCORAN, JFUS CHEN - EP Patent 1,385,052, 2004 - freepatentsonline.com

... and horizontal mask patterns and application of OPC techniques as ... The percentage

of flare was calculated using the following equation. Straylight % = E0 ...

Cached - Web Search

High numerical aperture lithographic imagery at the Brewster angle

TA Brunner, N Seong, WD Hinsberg, JA Hoffnagle, FA ... - Journal of Microlithography, Microfabrication, and

..., 2002 - link.aip.org

... by the pupil edge, defocus effects, image **flare** effects, stage ... mask will need more accurate **calculation** than that ... for optical proximity correction (**OPC**) methods ...

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The low-level radial velocity variability in Barnard's star (= GJ 699) - group of 5 »

M Kürster, M Endl, F Rouesnel, S Els, A Kaufer, S ... - A&A, 2003 - aanda.org

... For all data used in our calculation (Hip = Hipparcos, Nid = Nidever et al. ... H index

(middle spectrum offset by 0.5 flux units), and the flare event (upper ...

Cited by 22 - Related Articles - Cached - Web Search - BL Direct

The low-level radial velocity variability in Barnard's star (= GJ 699) - group of 6 »

M Kurster, M Endl, F Rouesnel, S Els, A Kaufer, S ... - A&A, 2003 - edpsciences.org

... For all data used in our **calculation** (Hip = Hipparcos, Nid = Nidever et al. ... H α index (middle spectrum offset by 0.5 flux units), and the **flare** event (upper ...

Cited by 18 - Related Articles - Web Search

Enhancements in rigorous simulation of light diffraction from phase-shift masks - group of 4

<u>»</u>

A Erdmann, N Kachwala - Proc. SPIE, 2002 - sigma-c.de

... thin masks there is no necessity to perform a new calculation of the ... This occurs

for subresolution features on optical proximity corrected (OPC) masks, for ...

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IEEE STD	IEEE Standard			Kobayashi, N.; Microelectronic Test Structures 22-25 March 2004 Page(s):23	-	CMTS '04, The International Co	nference on	
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			2.	Transistor flaring in deep su Singhal, V.; Keshav, C.B.; Sun Design Automation Conference International Conference on Vi 7-11 Jan. 2002 Page(s):299 - 3 Digital Object Identifier 10.110	nanth, K.G.; Suresh, P.I e. 2002, Proceedings o LSI Design, Proceeding 304	R.; f ASP-DAC 2002, 7th Asia and 9 is.	South Pacific	and the 15th
				AbstractPlus Full Text: PDF(1 Rights and Permissions	1113 KB) IEEE CNF			
			3.	FPGA as Process Monitor-ar performance and yield Xiao-Yu Li; Feng Wang; La, T. Semiconductor Manufacturing, Volume 17, Issue 3, Aug. 200 Digital Object Identifier 10.110	; Zhi-Min Ling; JEEE <u>Transactions on</u> 04 Page(s):267 - 272	characterize poly gate CD vari	ation and its	Impact on product
				AbstractPlus References Fu Rights_and_Permissions		IEEE JNL		
		Γ.	4.	A redundancy method of AS Hyunjeong Lee; Byungsun Lee Advanced Communication Tec Volume 2, 2004 Page(s):833 - Digital Object Identifier 10.110	e; chnology, 2004. The 6th 837		eme	
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			5.		a; Zhi-Min Ling; Ji-Fu K 2003 IEEE Internation	CD variation and its impact or lung; Wang, M.H.; Horng Nan Cl al Symposium on	•	•
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		Г	6.	A pattern matching system for Gennari, F.E.; Neureuther, A.R.		EDA		

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Nanolithography,	97%	1.	pattern layouts
MEMS, and MOEMS			Dongseok Nam, Eunmi Lee, Sung-gon Jung, Young S. Kang, Gisung Yeo, Junghyun Lee, Hanku ,
J. Applied Remote			Cho, Woo-Sung Han, and Joo-Tae Moon Proc. SPIE 4691 , 57 (2002) Full Text: [PDF (803 kB)] (10 pages)
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	92%	6.	flare in EUV lithography systems
			Manish Chandhok, Sang H. Lee, Christof G. Krautschik, Guojing Zhang, Bryan J. Rice, Michael Goldstein, Eric Panning, Robert Bristol, Alan R. Stivers, and Melissa Shell
			Proc. SPIE 5374 , 854 (2004) Full Text: [PDF-(100 kB)] (7 pages)
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	91%	7.	Measuring and modeling flare in optical lithography
•			Chris A. Mack Proc. SPIE 5040 , 151 (2003) Full Text: [PDF (88 kB)] (11 pages)
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		 ,	system Young-Je Yun, Ju-Hyung Moon, Haeng-Leem Jeon, Jea-Hee Kim, and Keeho Kim
			Proc. SPIE 6154 , 615435 (2006) Full Text: [PDF (531 kB)] (7 pages)

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